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(12) **United States Design Patent**
Koppa et al.

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(54) **PROCESS SHIELD FOR A SUBSTRATE
PROCESSING CHAMBER**

3/30; H01R 13/20; H01R 13/56; H01R
35/00

See application file for complete search history.

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Primary Examiner — Elizabeth J Oswecki

(**) Term: **15 Years**

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(51) **LOC (12) Cl.** **13-03**

(57) **CLAIM**

(52) **U.S. Cl.**

The ornamental design for a process shield for a substrate
processing chamber, as shown and described.

USPC **D13/182**

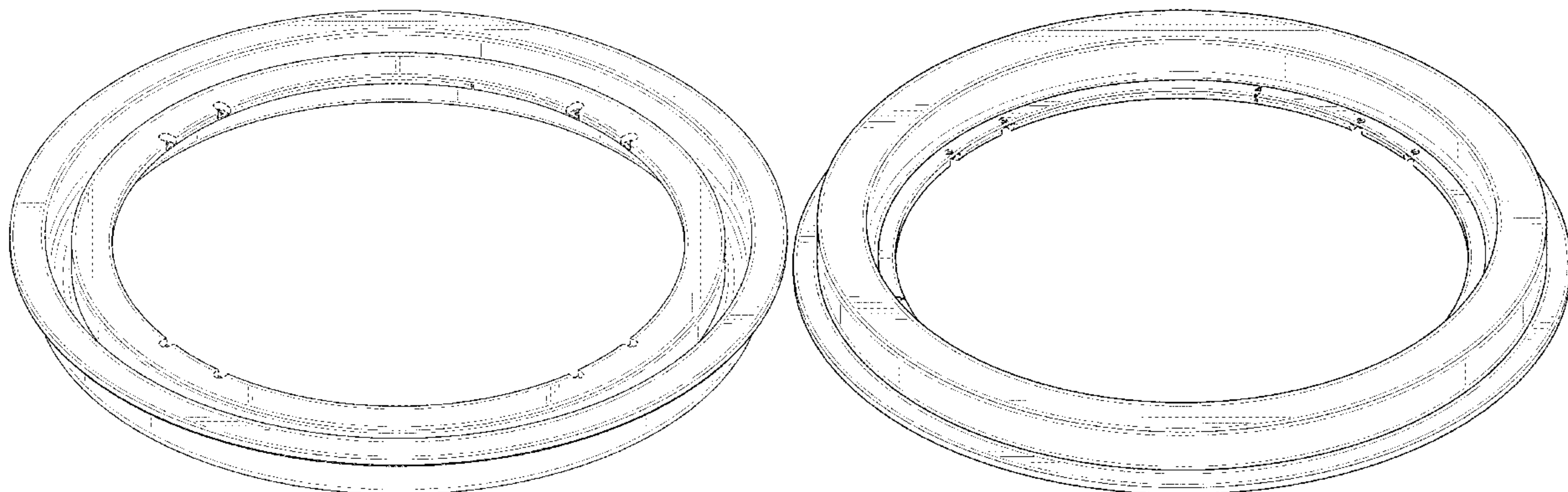
(58) **Field of Classification Search**

DESCRIPTION

USPC D13/182, 184, 162, 199, 118, 122, 133;
D24/232; 118/724, 725, 728, 729, 730,
118/733; 156/345.51, 345.52, 345.53
CPC C23C 16/455; C23C 16/45502; C23C
16/45517; C23C 16/4582; C23C 16/4583;
C23C 16/4584; C23C 16/4585; C23C
16/4401; C23C 16/4402; C23C 16/4409;
C23C 16/00; H01L 21/50; H01L 21/4817;
H01L 21/4871; H01L 21/563; H01L
21/683; H01L 23/02; H01L 23/04; H01L
23/12; H01L 23/13; H01L 23/14; H01L
23/06; H01L 23/10; H01L 23/42; H05K

FIG. 1 is a top isometric view of a process shield for a
substrate processing chamber, showing our new design;
FIG. 2 is a bottom isometric view thereof;
FIG. 3 is a top plan view thereof;
FIG. 4 is a bottom plan view thereof;
FIG. 5 is a front elevation view thereof;
FIG. 6 is a back elevation view thereof;
FIG. 7 is a left side elevation view thereof;
FIG. 8 is a right side elevation view thereof; and,
FIG. 9 is an enlarged cross sectional view taken along line
9-9 in FIG. 3.

(Continued)



The dashed lines in FIGS. 1-9 represent unclaimed environment forming no part of the claimed design.

1 Claim, 9 Drawing Sheets

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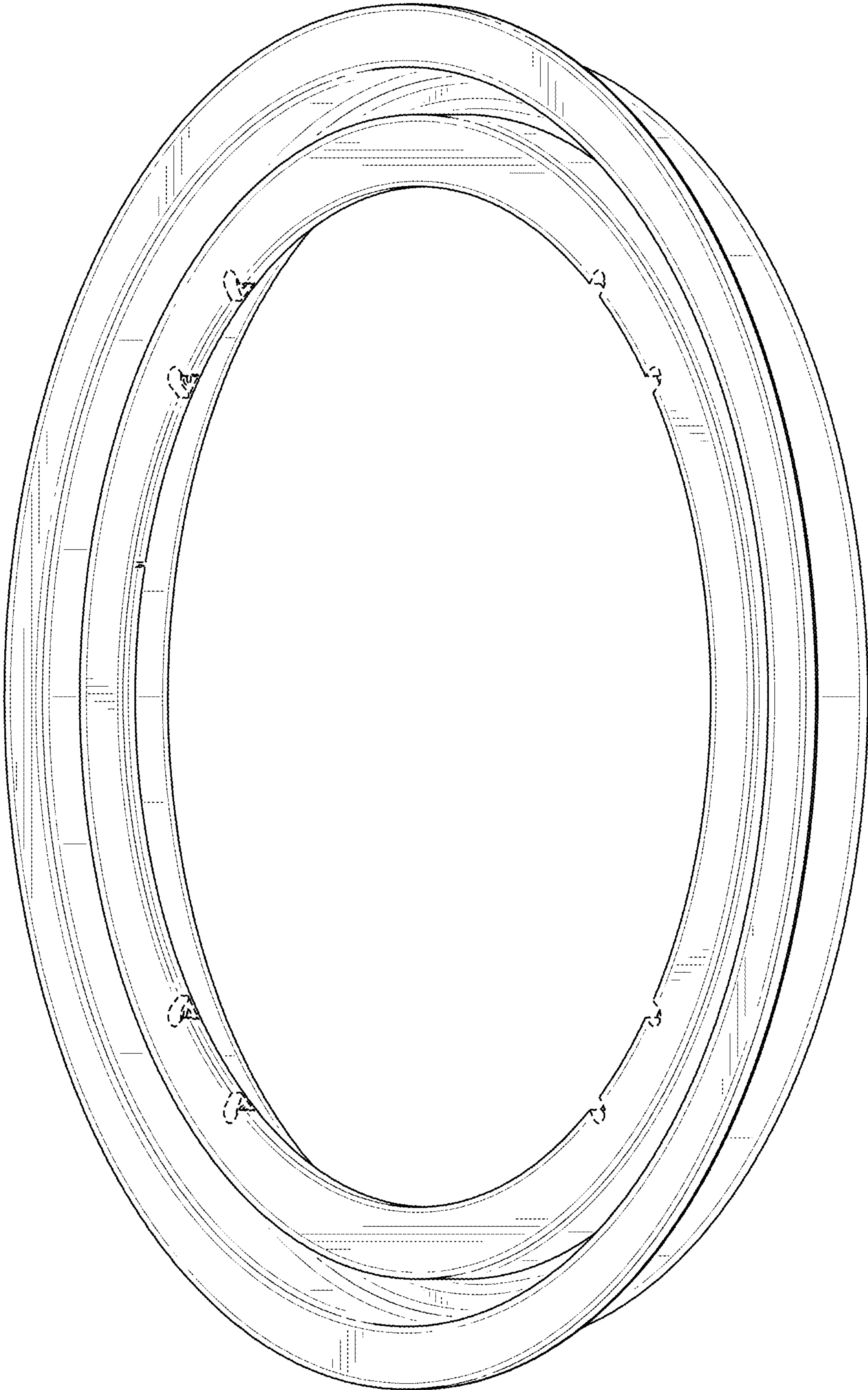


FIG. 1

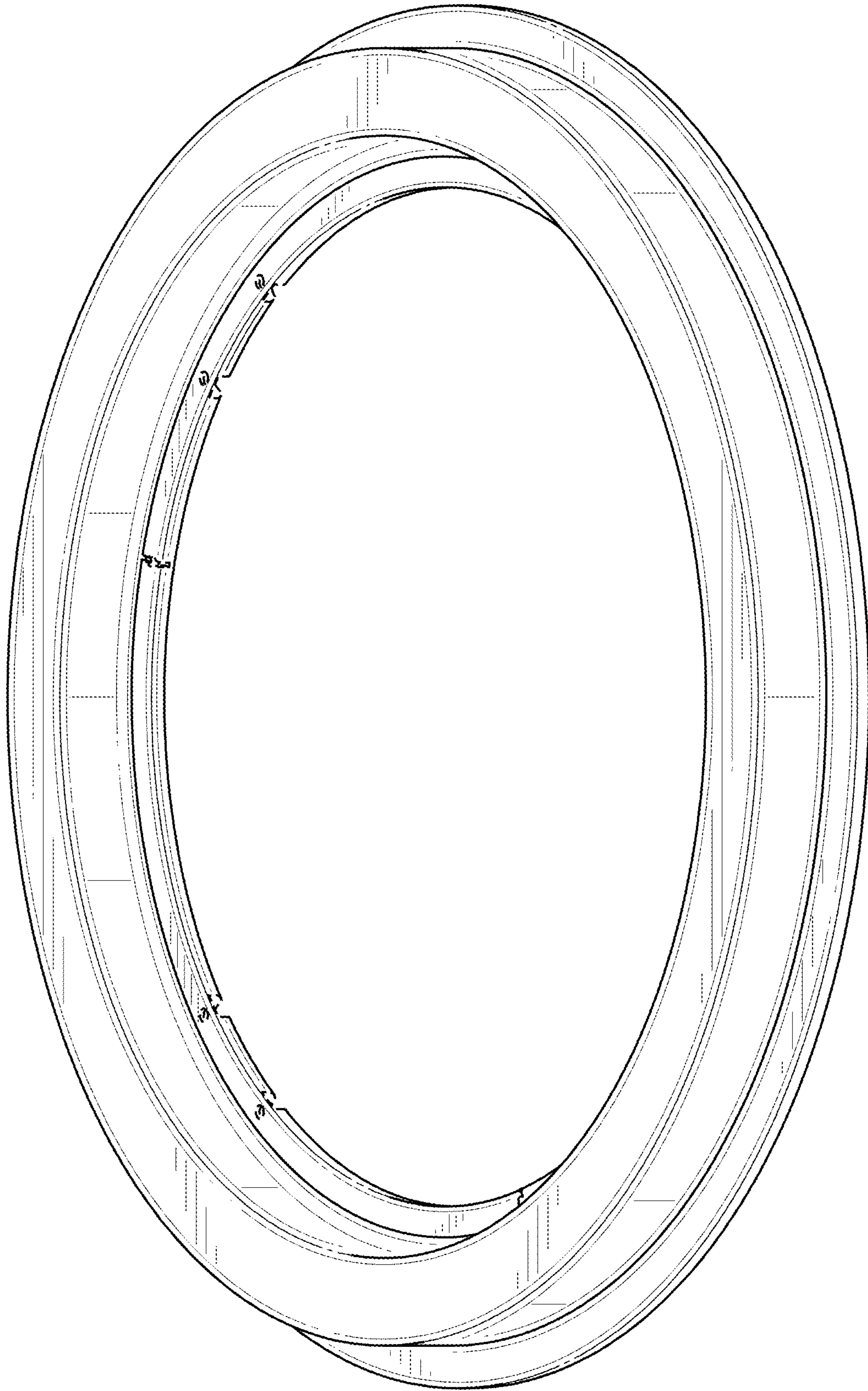


FIG. 2

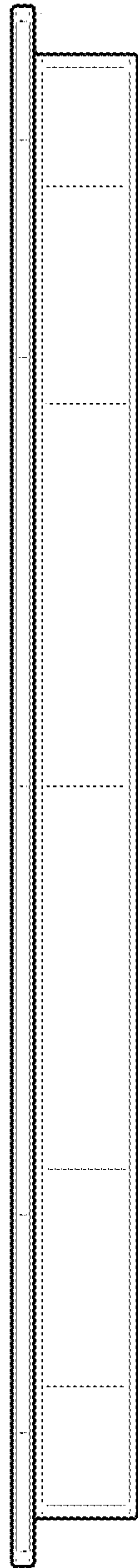


FIG. 3

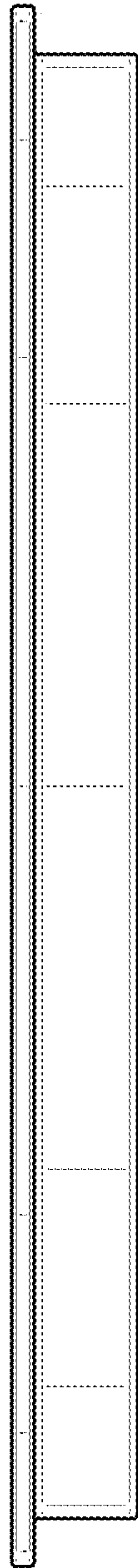


FIG. 4

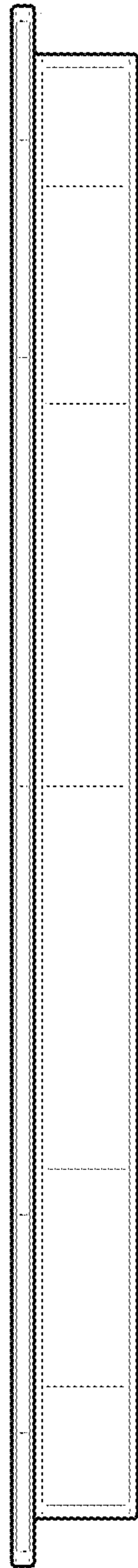


FIG. 5

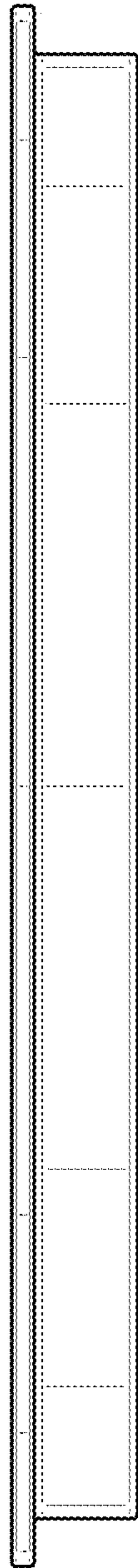


FIG. 6

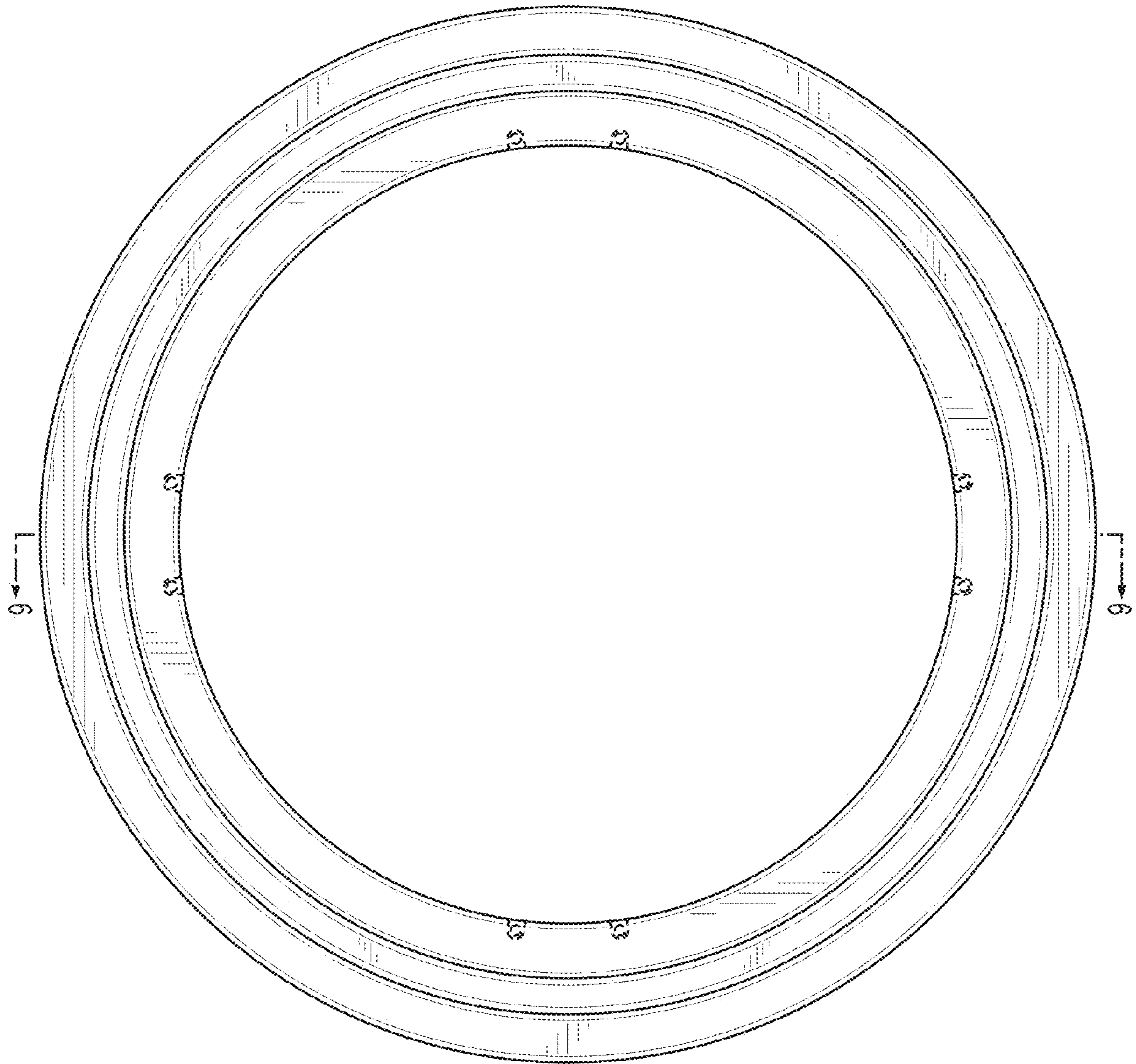


FIG. 7

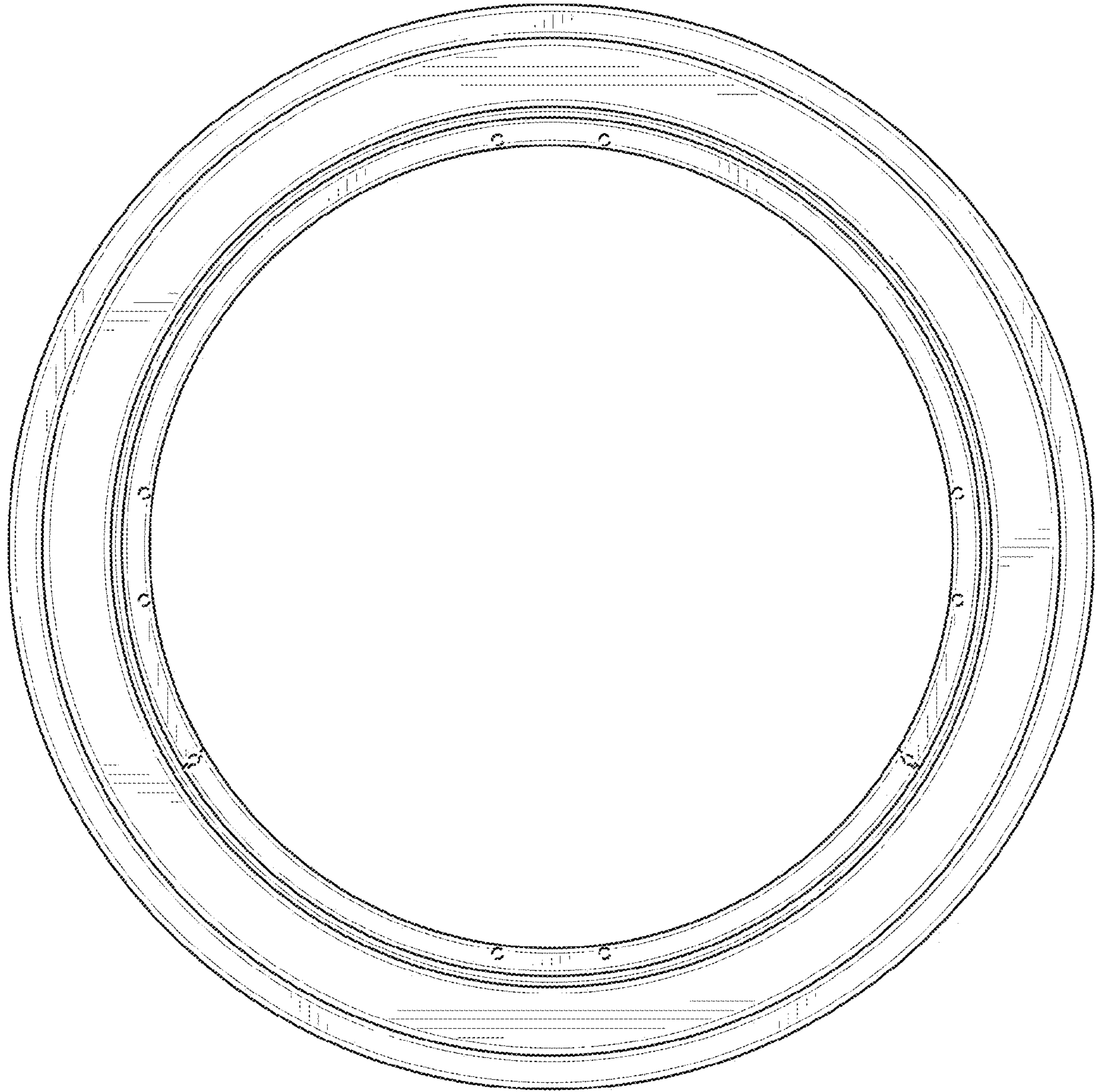


FIG. 8

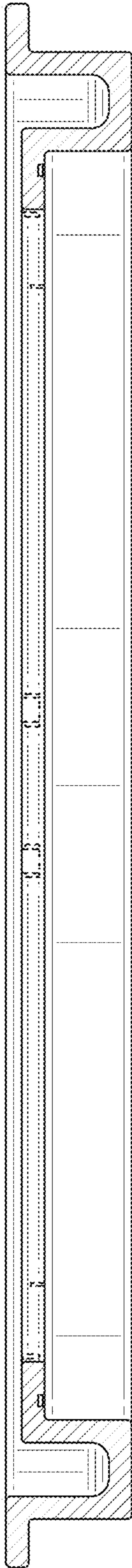


FIG. 9